

X3G-OH047; X3T-OH047; X3G-OH048; X3T-OH048

Magnetic field sensor

Rev. 1 — 4 April 2011

Product specification

1. Product profile

1.1 General description

The X3G-OH047, X3G-OH048, X3T-OH047 and X3T-OH048 are sensitive magnetic field sensors, employing the magneto-resistive effect of thin film permalloy. The sensors contain two parallel supplied Wheatstone bridges at a relative angle of 45° to each other.

A rotating magnetic field in the surface parallel to the chip (x-y plane) will deliver two independent sinusoidal output signals, one following a $\cos(2\alpha)$ and the other following a $\sin(2\alpha)$ function, α being the angle between sensor and field direction (see [Figure 5](#) and [Figure 6](#)).

The X3G-OH047, X3G-OH048, X3T-OH047 and X3T-OH048 are suited for high precision angle measurement applications under low field conditions (saturation field strength 25 kA/m).

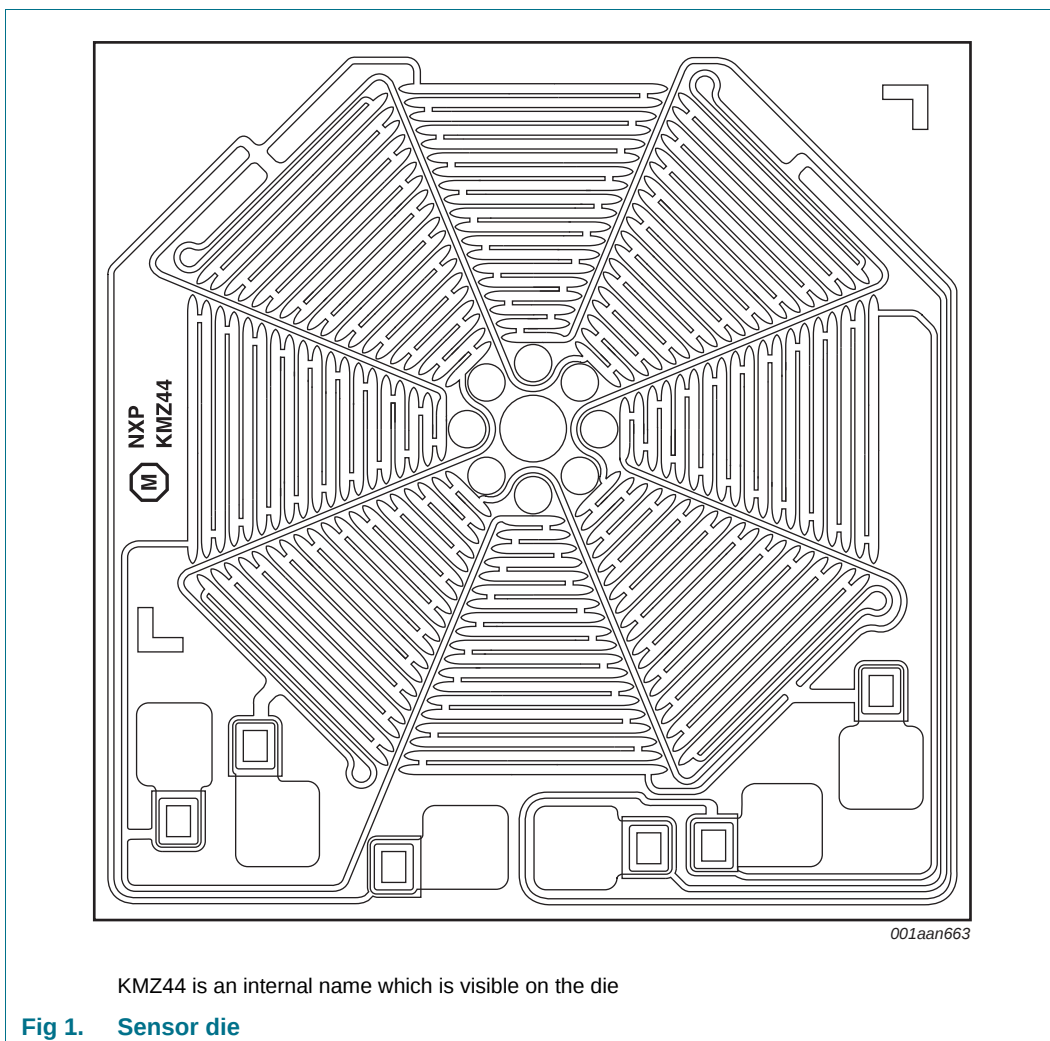
The sensors can be operated at any frequency between DC and 1 MHz.

All type numbers shown in this data sheet are valid for a single-die (single sensor). The double-die has two magnetic field sensors with electrical and magnetic parameters which fulfill the specified single-die values and do not correlate to each other.

Table 1. Product overview

Type number	Sensor	Packing
X3G-OH047	double-die	sawn wafer; on foil
X3G-OH048	single-die	sawn wafer; on foil
X3T-OH047	double-die	taped on reel
X3T-OH048	single-die	taped on reel





1.2 Features and benefits

- Accurate and reliable angle measurement
- Mechanical robustness, contactless principle
- Wear-free operation
- Accuracy independent of mechanical tolerances
- Extended temperature range

1.3 Applications

- | | |
|------------------------------|----------------------|
| ■ Steering angle and torsion | ■ Window wipers |
| ■ Headlight adjustment | ■ Fuel level |
| ■ Motor positioning | ■ Mirror positioning |

1.4 Quick reference data

Table 2. Quick reference data

$T_{amb} = 25\text{ }^{\circ}\text{C}$; $H_{ext} = 25\text{ kA/m}$; $V_{CC} = 5\text{ V}$; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		-	5	9	V
V_M	peak voltage	see Figure 3	[1][2] 60	67	75	mV
V_{offset}	offset voltage	per supply voltage; see Figure 3	[1] -2	-	+2	mV/V
$TC_{V(offset)}$	offset voltage temperature coefficient	per supply voltage; $T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+150\text{ }^{\circ}\text{C}$; see Figure 3	[1][3] -2	-	+2	($\mu\text{V/V/K}$)
R_{bridge}	bridge resistance		[1][4] 2.7	3.2	3.7	k Ω

[1] Applicable for bridge 1 and bridge 2.

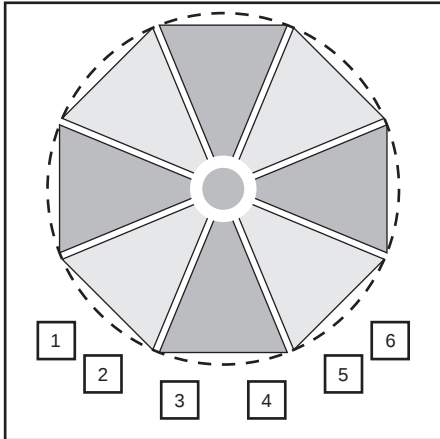
[2] $V_M = |V_{O(max)} - V_{offset}|$. Periodicity of V_M : $\sin(2\alpha)$ and $\cos(2\alpha)$, respectively.

[3] $TC_{V(offset)} = \frac{V_{offset}(at\ 150\text{ }^{\circ}\text{C}) - V_{offset}(at\ -40\text{ }^{\circ}\text{C})}{150\text{ }^{\circ}\text{C} - (-40\text{ }^{\circ}\text{C})}$

[4] Bridge resistance between pad 5 to pad 1 and pad 4 to pad 2.

2. Pinning information

Table 3. Pinning

Pad	Symbol	Description	Simplified outline
1	ON1	output voltage bridge 1	
2	ON2	output voltage bridge 2	
3	GND	common ground	
4	OP2	output voltage bridge 2	
5	OP1	output voltage bridge 1	
6	V_{CC}	common bridge supply voltage	

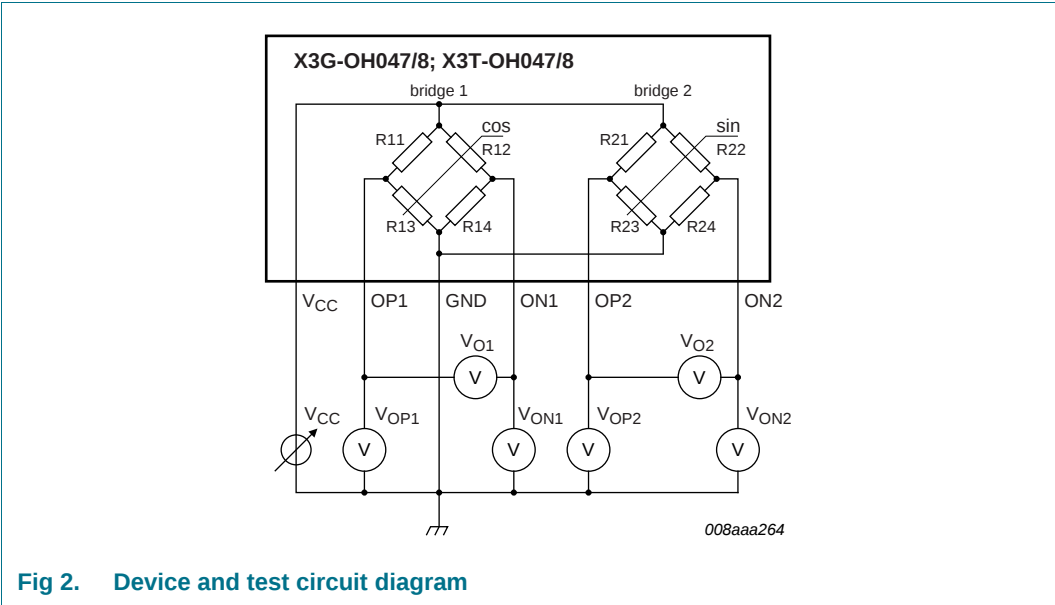
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3. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
X3G-OH047	bare die	double-die; sawn wafer; on foil	OL-X3G-OH047
X3G-OH048	bare die	single-die; sawn wafer; on foil	OL-X3G-OH048
X3T-OH047	bare die	double-die; taped on reel	OL-X3T-OH047
X3T-OH048	bare die	single-die; taped on reel	OL-X3T-OH048

4. Circuit diagram



5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-	9	V
H_{ext}	external magnetic field strength	[1]	25	-	kA/m
T_{amb}	ambient temperature		-40	+150	°C

[1] Minimum stimulating magnetic field parallel to the chip surface (x-y plane) to achieve specified angular accuracy.

6. Characteristics

Table 6. Characteristics

$T_{amb} = 25\text{ °C}$; $H_{ext} = 25\text{ kA/m}$ ^[1]; $V_{CC} = 5\text{ V}$; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		-	5	9	V
V_M	peak voltage	see Figure 3	[2][3] 60	67	75	mV
TC_{VM}	peak voltage temperature coefficient	$T_{amb} = -40\text{ °C to }+150\text{ °C}$	[2][4] -0.30	-0.36	-0.42	%/K
R_{bridge}	bridge resistance		[2][5] 2.7	3.2	3.7	kΩ
$TC_{R(bridge)}$	bridge resistance temperature coefficient	$T_{amb} = -40\text{ °C to }+150\text{ °C}$	[2][6] 0.24	0.27	0.29	%/K
V_{offset}	offset voltage	per supply voltage; see Figure 3	[2] -2	-	+2	mV/V
$TC_{V(offset)}$	offset voltage temperature coefficient	per supply voltage; $T_{amb} = -40\text{ °C to }+150\text{ °C}$; see Figure 3	[2][7] -2	-	+2	(μV/V)/K
$V_{o(hys)}$	hysteresis output voltage	see Figure 4	[2][8] 0	0.05	0.18	%FS
ω	angular velocity		0	-	1	MHz
k	amplitude synchronism		[9] 98.9	100	101.1	%
TC_k	amplitude synchronism temperature coefficient	$T_{amb} = -40\text{ °C to }+150\text{ °C}$	[10] -0.01	0	+0.01	%/K
$\Delta\alpha$	angular inaccuracy		[11] 0	0.05	0.1	deg

[1] Minimum stimulating magnetic field parallel to the chip surface (x-y plane) to achieve angular inaccuracy.

[2] Applicable for bridge 1 and bridge 2.

[3] $V_M = |V_{O(max)} - V_{offset}|$. Periodicity of V_M : $\sin(2\alpha)$ and $\cos(2\alpha)$, respectively.

$$[4] \quad TC_{VM} = \frac{V_M(at\ 150\text{ °C}) - V_M(at\ -40\text{ °C})}{V_M(at\ 25\text{ °C}) \times (150\text{ °C} - (-40\text{ °C}))}$$

[5] Bridge resistance between pad 5 to pad 1 and pad 4 to pad 2.

$$[6] \quad TC_{R(bridge)} = \frac{R_{bridge}(at\ 150\text{ °C}) - R_{bridge}(at\ -40\text{ °C})}{R_{bridge}(at\ 25\text{ °C}) \times (150\text{ °C} - (-40\text{ °C}))}$$

$$[7] \quad TC_{V(offset)} = \frac{V_{offset}(at\ 150\text{ °C}) - V_{offset}(at\ -40\text{ °C})}{150\text{ °C} - (-40\text{ °C})}$$

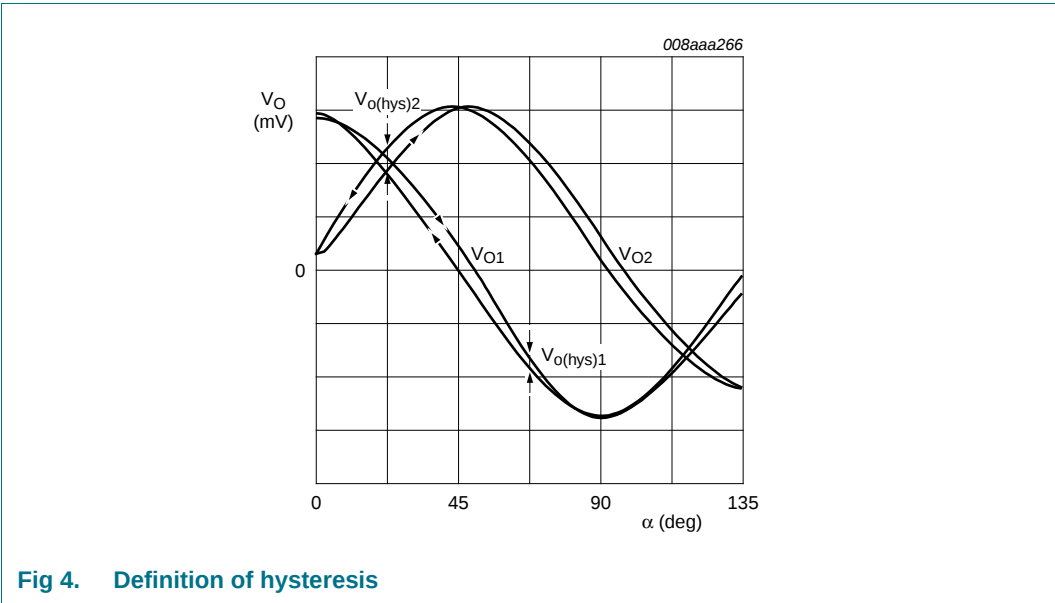
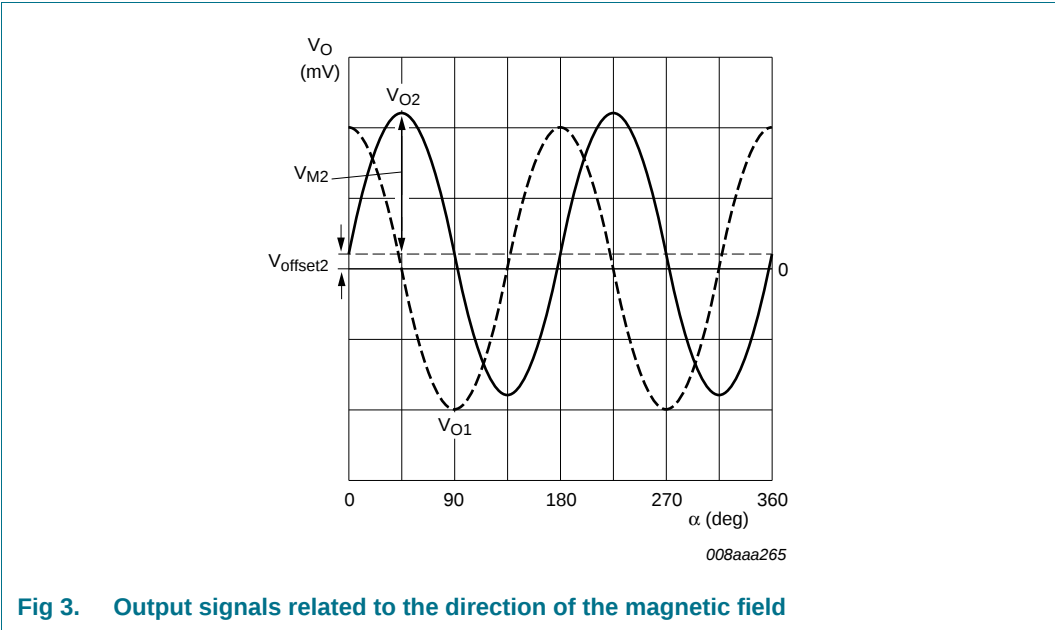
$$[8] \quad V_{o(hys)1} = \left| \frac{V_{O1}(67.5^\circ)135^\circ \rightarrow 45^\circ - V_{O1}(67.5^\circ)45^\circ \rightarrow 135^\circ}{2 \times V_{M1}} \right|$$

$$V_{o(hys)2} = \left| \frac{V_{O2}(22.5^\circ)90^\circ \rightarrow 0^\circ - V_{O2}(22.5^\circ)0^\circ \rightarrow 90^\circ}{2 \times V_{M2}} \right|$$

$$[9] \quad k = \frac{V_{M1}}{V_{M2}}$$

$$[10] \quad TC_k = \frac{k(at\ 150\text{ °C}) - k(at\ -40\text{ °C})}{k(at\ 25\text{ °C}) \times (150\text{ °C} - (-40\text{ °C}))}$$

[11] $\Delta\alpha = |\alpha_{real} - \alpha_{meas}|$; $V_{offset} = 0\text{ V}$; inaccuracy of angular measurement due to deviations from ideal sinusoidal characteristics, calculated from the third and fifth harmonics of the spectrum V_O .



7. Bare die outline

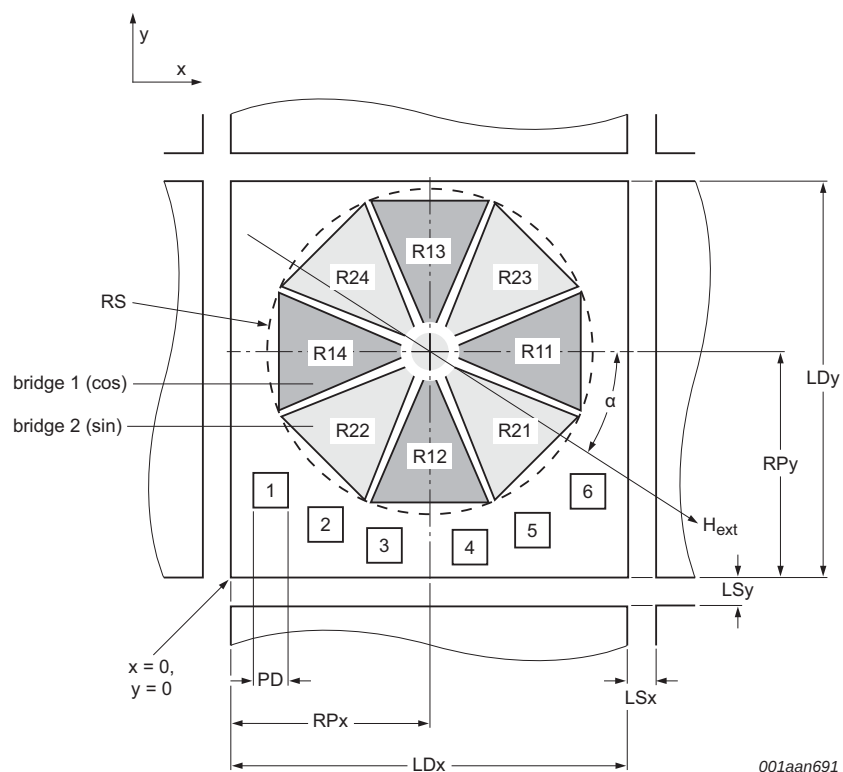
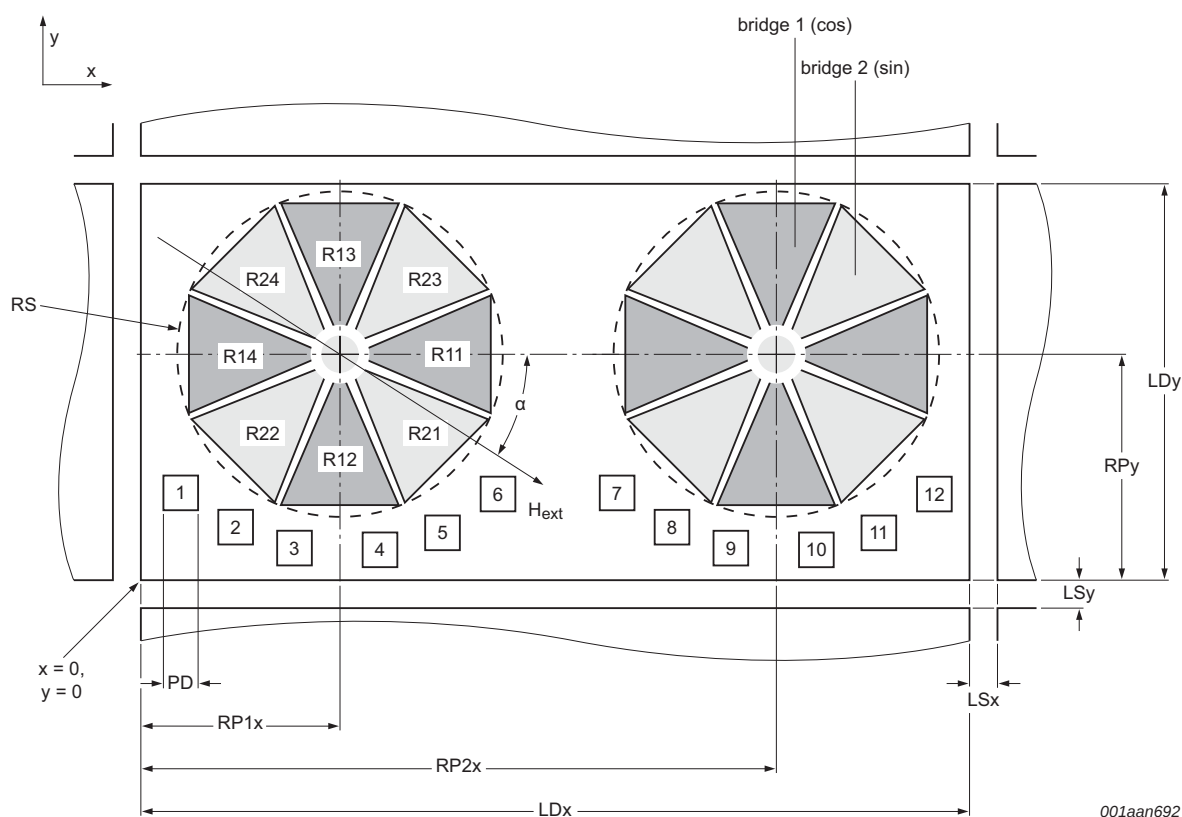


Fig 5. Bare die outline (single die)

Table 7. Mechanical dimensions for [Figure 5](#)

Symbol	Parameter	x	y	Radius/diameter	Unit
LD	die size	1150	1150	-	μm
LS	sawing lane width	60	60	-	μm
RP	reading point position	575	642	-	μm
RS	sensitive area radius	-	-	480	μm
PD	pad diameter	-	-	110	μm
1	position pad 1	108	230	-	μm
2	position pad 2	243	125	-	μm
3	position pad 3	489	95	-	μm
4	position pad 4	632	95	-	μm
5	position pad 5	900	125	-	μm
6	position pad 6	1032	200	-	μm



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Fig 6. Bare die outline (double die)

Table 8. Mechanical dimensions for Figure 6

Symbol	Parameter	x	y	Radius/diameter	Unit
LD	die size	2360	1150		μm
LS	sawing lane width	60	60		μm
RP1	reading point position 1	575	642		μm
RP2	reading point position 2	1785	642		μm
RS	sensitive area radius	-	-	480	μm
PD	pad diameter	-	-	110	μm
1	position pad 1	108	230		μm
2	position pad 2	243	125		μm
3	position pad 3	489	95		μm
4	position pad 4	632	95		μm
5	position pad 5	900	125		μm
6	position pad 6	1032	200		μm
7	position pad 7	1318	230		μm
8	position pad 8	1453	125		μm
9	position pad 9	1699	95		μm

Table 8. Mechanical dimensions for Figure 6 ...continued

Symbol	Parameter	x	y	Radius/diameter	Unit
10	position pad 10	1842	95		μm
11	position pad 11	2110	125		μm
12	position pad 12	2242	200		μm

Table 9. Wafer dimensions

Symbol	Parameter	Value	Unit
WD	wafer diameter	150	mm
WT	wafer thickness	380 ± 15	μm

8. Packing information

8.1 Tape construction for X3G-OH047 and X3G-OH048

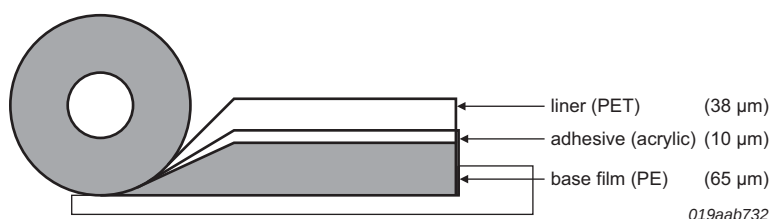


Fig 7. Tape construction

Table 10. Material composition

Parameter	Content	Typical value	Unit
Total thickness	-	75	μm
Adhesion	-	55 / 20	g/mm
Ionic impurity	Na ⁺	0.027	μg/ml
	K ⁺	< 0.004	μg/ml
	Cl	0.045	μg/ml

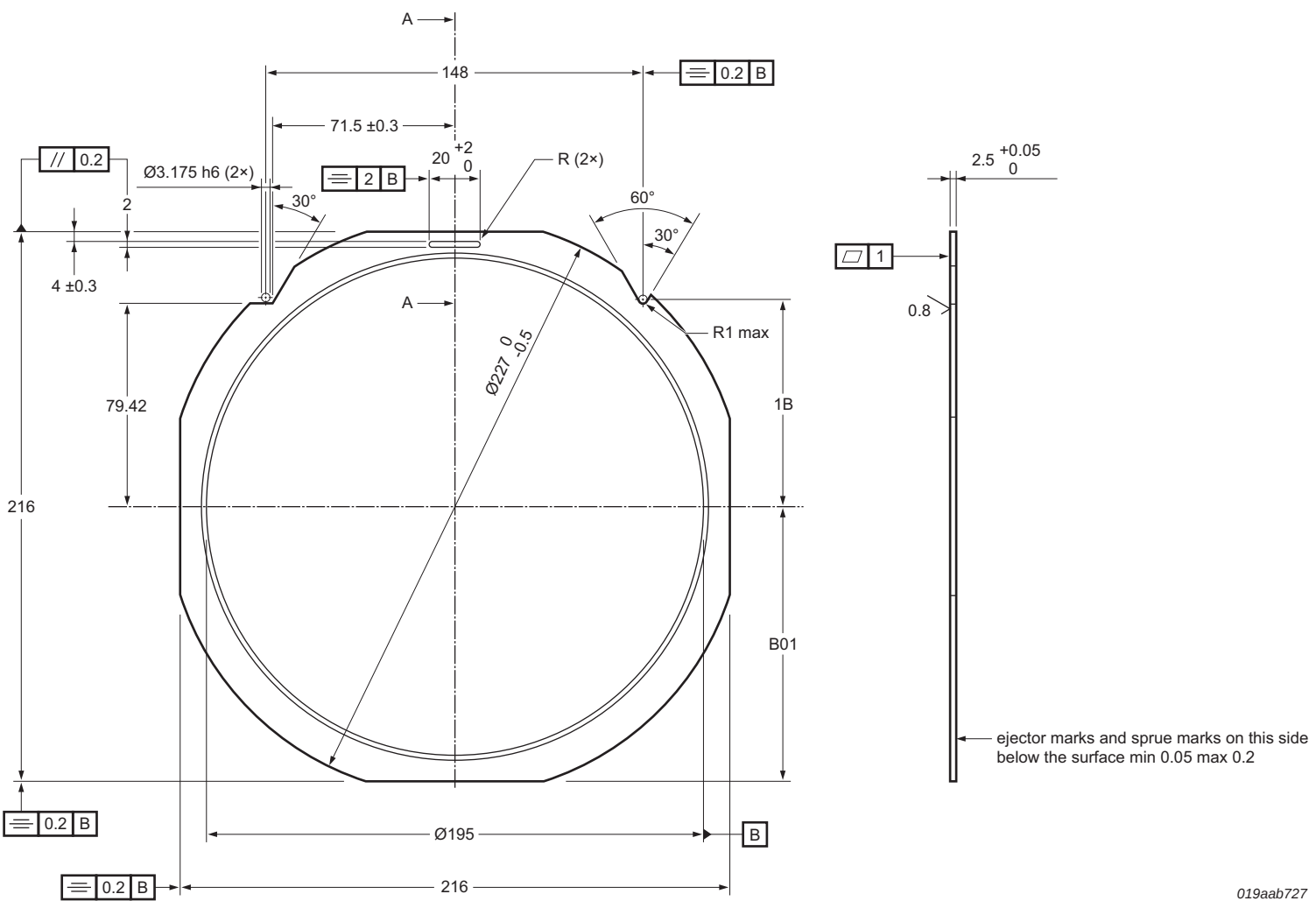
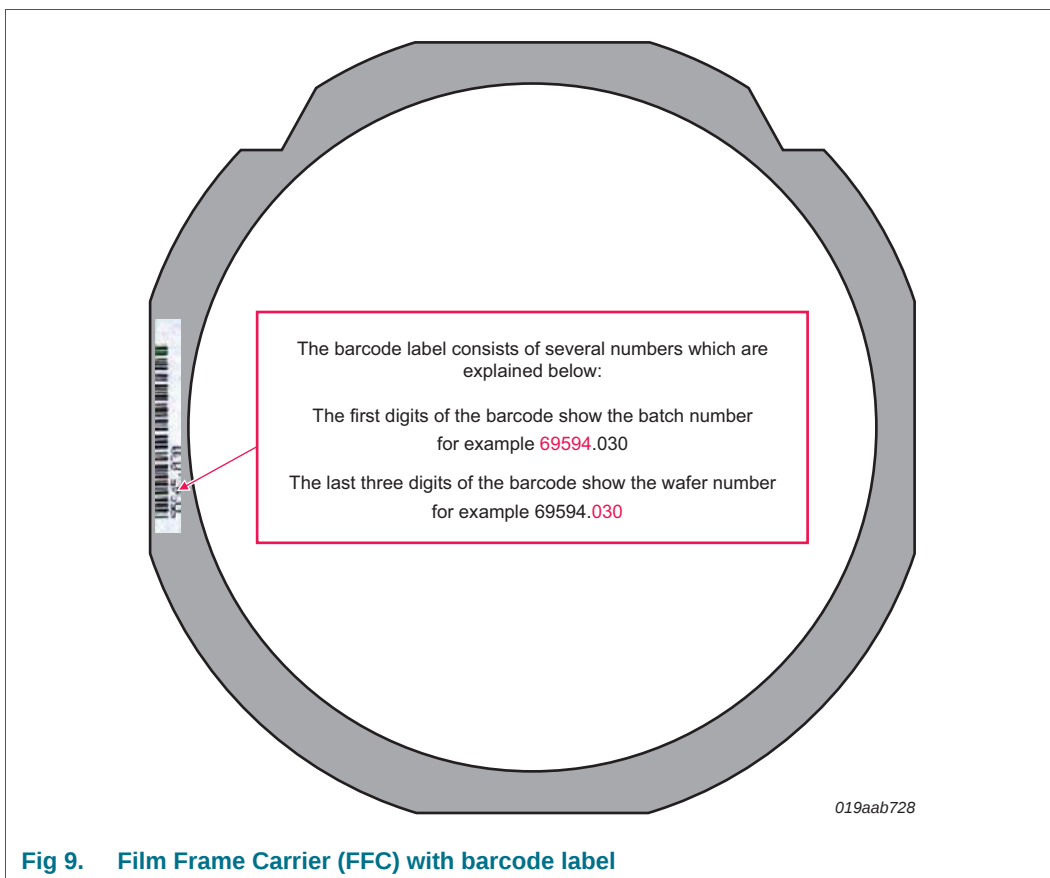
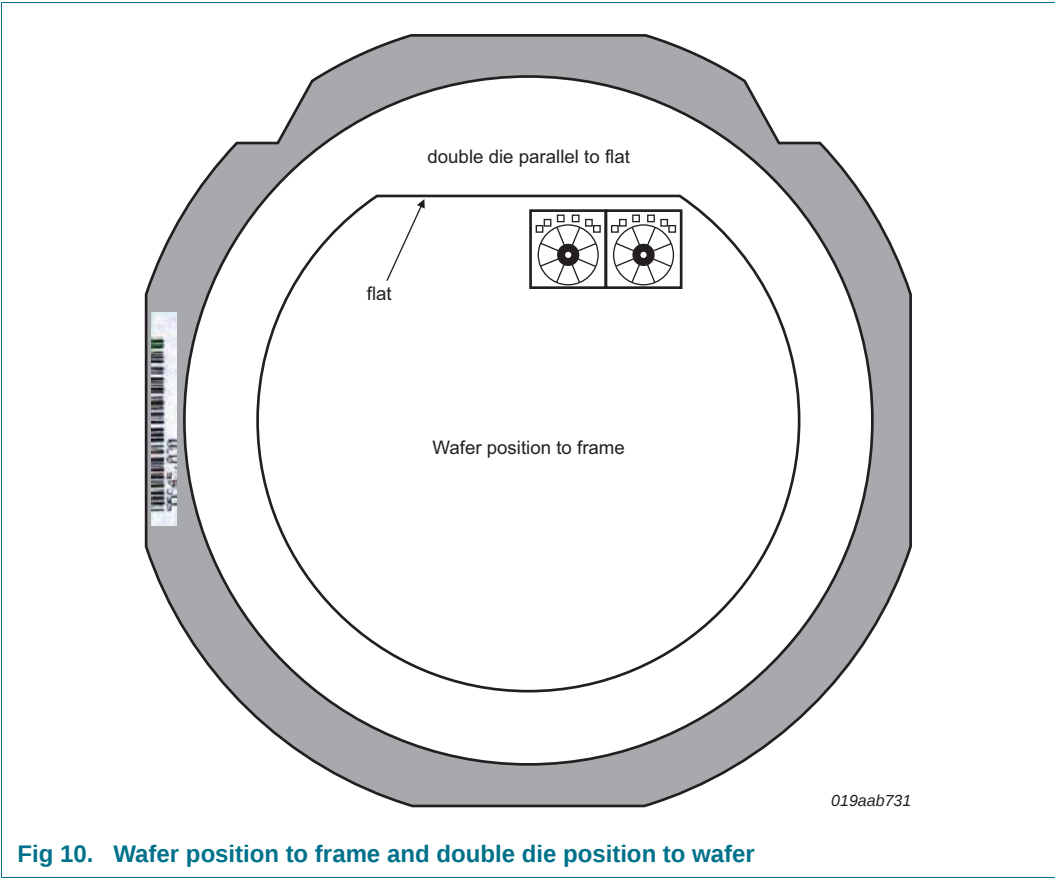


Fig 8. Geometrical dimensions of frame





8.2 Carrier tape for X3T-OH047 and X3T-OH048

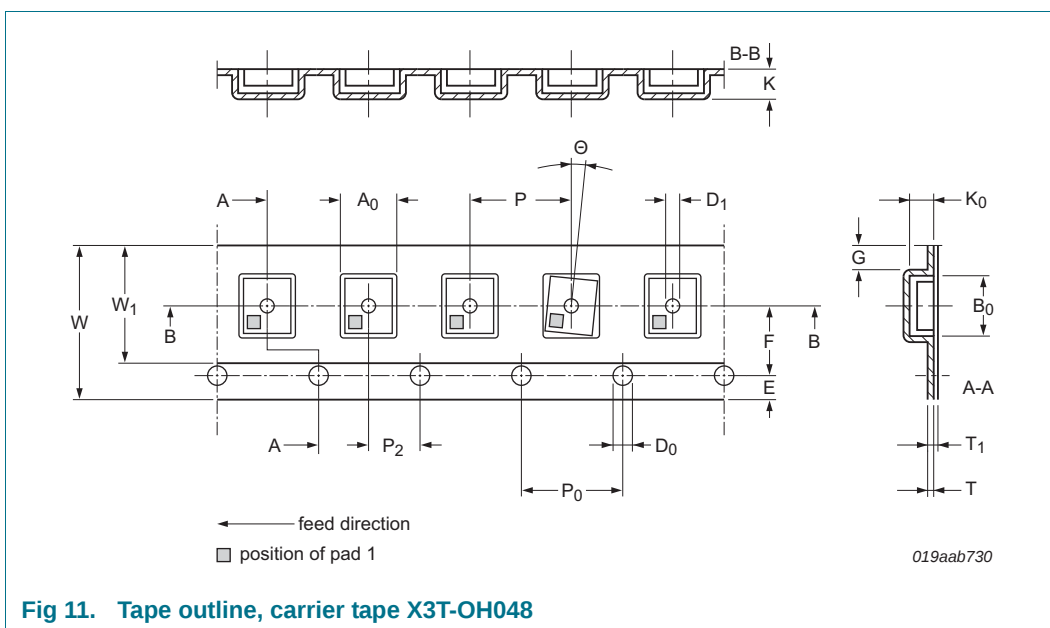


Fig 11. Tape outline, carrier tape X3T-OH048

Table 11. Dimensions for [Figure 11 "Tape outline, carrier tape X3T-OH048"](#)

Item	Symbol	Specification	
		Dimension [mm]	Tolerance
Overall dimensions			
Tape width	W	8	±0.1
Thickness	K	≤ 1.2	-
Distance	G	≥ 0.75	-
Sprocket holes			
Diameter	D ₀	1.5	±0.1
Distance	E	1.75	±0.1
Pitch ^[1]	P ₀	4	±0.1
Distance between center lines			
Length direction	P ₂	2	±0.05
Width direction	F	3.5	±0.05
Compartments			
Length	A ₀	1.4	±0.05
Width	B ₀	1.4	±0.05
Depth	K ₀	0.8	±0.05
Hole diameter	D ₁	0.5	±0.1
Pitch	P	4	±0.1
Device			
Outline	X3T-OH048		
Rotation	Θ	≤ 20°	-
Carrier tape antistatic			
Film thickness ^[2]	T	0.25	±0.07

Table 11. Dimensions for [Figure 11 “Tape outline, carrier tape X3T-OH048”](#) ...continued

Item	Symbol	Specification	
		Dimension [mm]	Tolerance
Cover tape			
Width	W ₁	≤ 5.75	-
Film thickness	T ₁	≤ 0.1	-
Bending radius			
In winding direction	R	≥ 30	-

- [1] Cumulate pitch error ± 0.2 over 10 pitch.
 [2] Carbon loaded polystyrene 100 % recyclable.

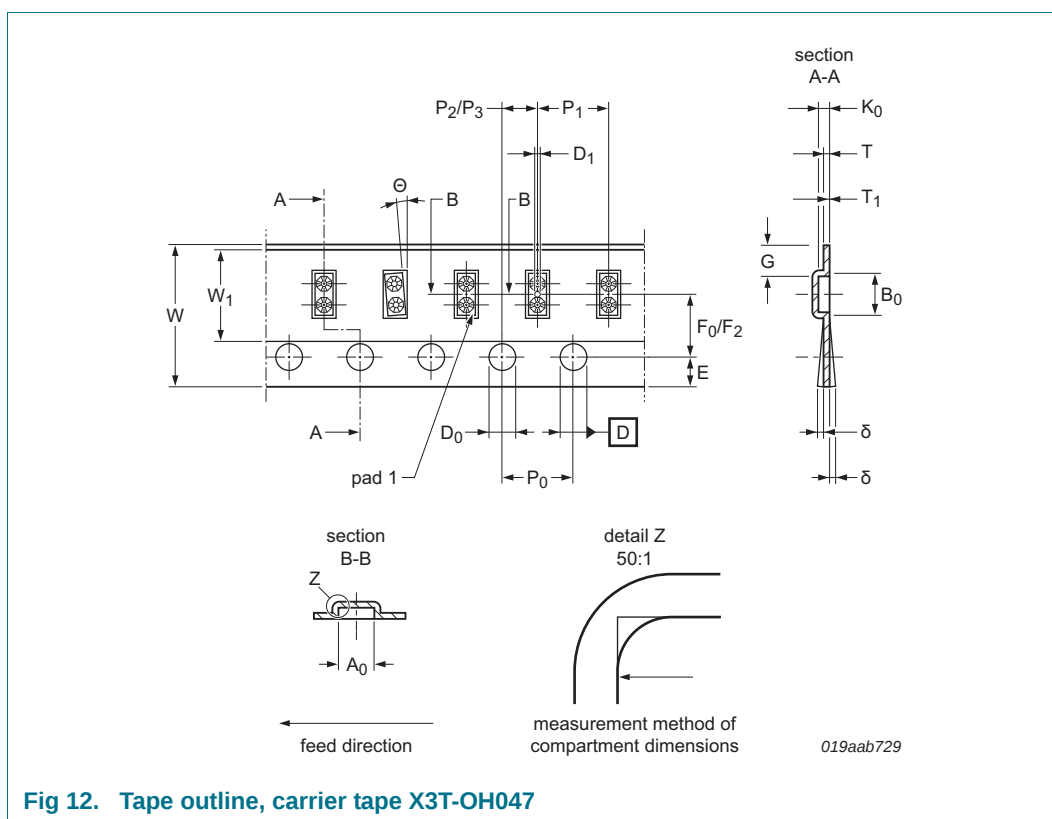


Fig 12. Tape outline, carrier tape X3T-OH047

Table 12. Dimensions for [Figure 12 “Tape outline, carrier tape X3T-OH047”](#)

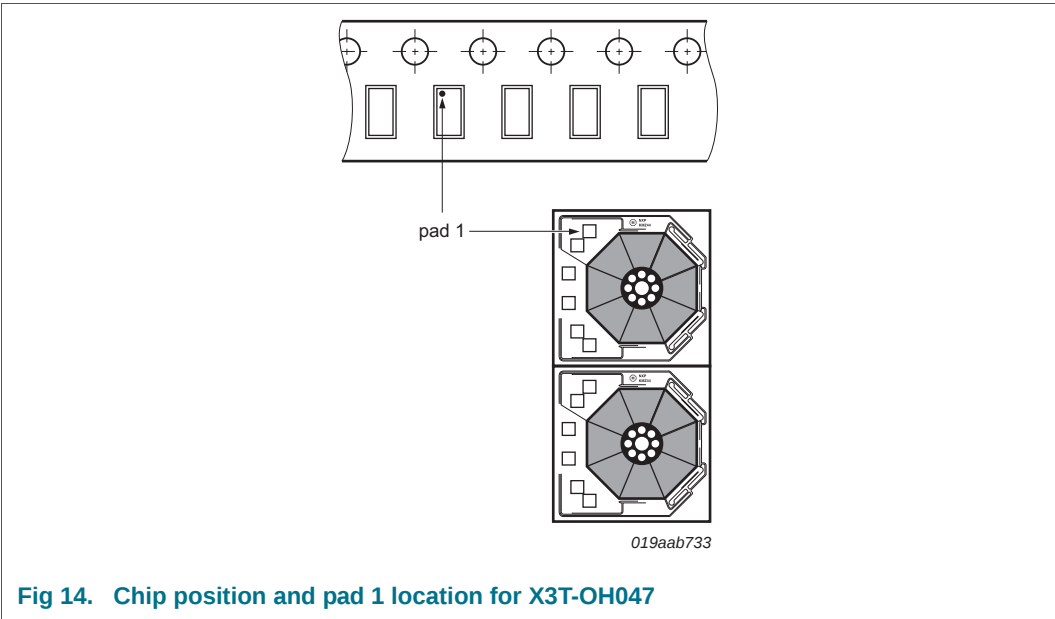
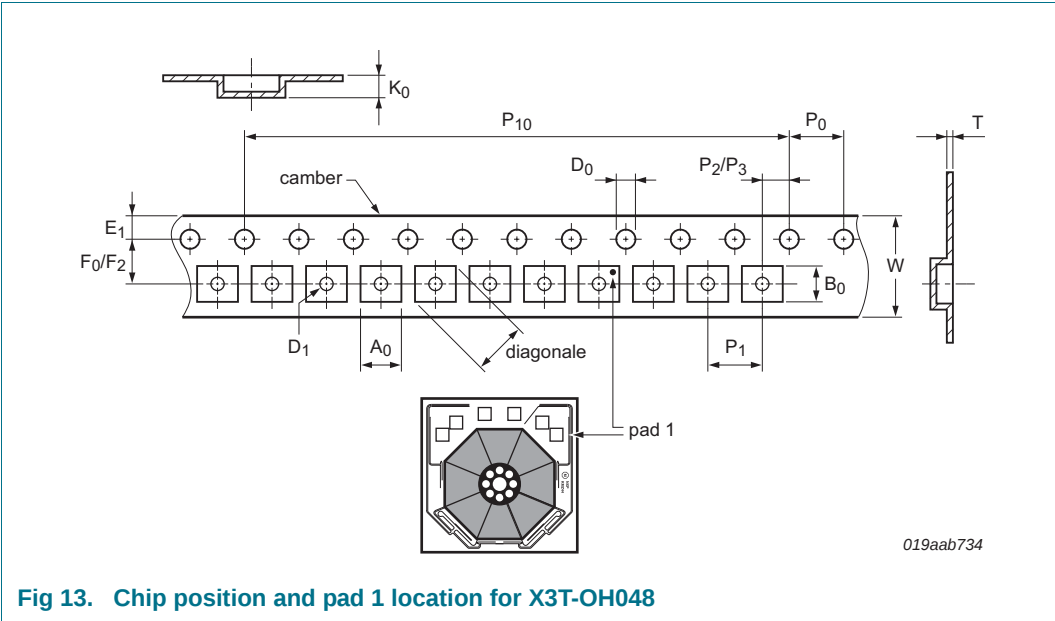
Item	Symbol	Specification	
		Dimension [mm]	Tolerance
Overall dimensions			
Tape width	W	8	±0.1
Distance	G	≥ 0.75	-
Sprocket holes			
Diameter	D ₀	1.5	±0.1
Distance	E	1.75	±0.1
Pitch ^[1]	P ₀	4	±0.1

Table 12. Dimensions for [Figure 12 “Tape outline, carrier tape X3T-OH047”](#) ...continued

Item	Symbol	Specification	
		Dimension [mm]	Tolerance
Distance between center lines			
Sprocket hole / cavity center	P ₂	2	±0.05
Sprocket hole / cavity hole	P ₃	2	±0.05
Sprocket hole / cavity center	F ₀	3.5	±0.05
Sprocket hole / cavity hole	F ₂	3.5	±0.05
Compartment			
Length	A ₀	1.4	±0.05
Width overall	B ₀	2.7	±0.05
Depth	K ₀	0.5	±0.05
Hole diameter	D ₁	0.5	±0.1
Pitch	P ₁	4	±0.1
Device			
Outline	X3T-OH047		
Rotation	Θ	≤ 15°	-
Carrier tape antistatic			
Film thickness ^[2]	T	0.25	±0.07
Bend	δ	≤ 0.3	-
Cover tape			
Width	W ₁	5.3	±0.1
Film thickness	T ₁	0.05	±0.01
Bending radius			
In winding direction	R	≥ 30	-

[1] Cumulate pitch error ±0.2 over 10 pitch.

[2] Carbon loaded polystyrene 100 % recyclable.



9. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
X3G_T_OH047_048 v.1	20110404	Product specification	-	-

10. Legal information

10.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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